

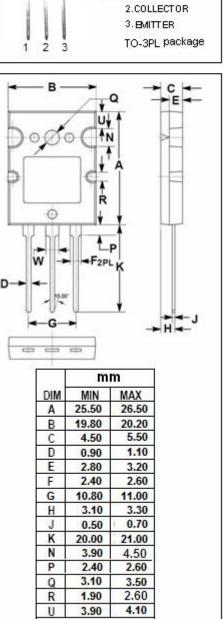
INCHANGE SEMICONDUCTOR

isc Silicon NPN Power Transistor

2SC3874

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High SvWide arMinimur	TION NPN triple diffusion planar type vitching Speed rea of safe operation m Lot-to-Lot variations for robust de ance and reliable operation	PIN 1. BASE 2.COLLEG 3. BMITTE 1 2 3 TO-3PL F				
	TIONS ed for high voltage high-speed swite TE MAXIMUM RATINGS(Ta=25℃)					
SYMBOL	PARAMETER	VALUE	UNIT			
V _{CBO}	Collector-Base Voltage	500	V			
V _{CEO}	Collector-Emitter Voltage	400	V			
V _{EBO}	Emitter-Base Voltage	7	V			
lc	Collector Current-Continuous	15	А	A 25.50 26.50 B 19.80 20.20 C 4.50 5.50		
Ісм	Collector Current-Pulse	25	А	D 0.90 1.10 E 2.80 3.20 F 2.40 2.60		
Pc	Collector Power Dissipation @ Tc=25°C	150	w	G 10.80 11.00 H 3.10 3.30 J 0.50 0.70 K 20.00 21.00		
TJ	Junction Temperature	150	°C	K 20.00 21.00 N 3.90 4.50 P 2.40 2.60 Q 3.10 3.50		
T _{stg}	Storage Temperature Range	-55~150	°C	Q 3.10 3.50 R 1.90 2.60 U 3.90 4.10 W 2.90 3.25		
	1		<u> </u>	0.20		



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ELECTRICAL CHARACTERISTICS

$T_{\rm C}\text{=}25^\circ\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 25mA; I _B = 0	500			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10A; I _B =2A			1.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 10A; I _B =2A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			10	μA
Іево	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	uA
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	15			
h _{FE-2}	DC Current Gain	I _C = 10A; V _{CE} = 5V	8			
t _{stg}	Storage Time				2	μ S
tr	Fall Time	I _C = 10A, I _{B1} =2A; I _{B2} = -4A			0.3	μ S

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